

200mA, 30V Low VF SMD Schottky Barrier Diode

FEATURES

- Low capacitance
- Low forward voltage drop
- Moisture sensitivity level: level 1, per J-STD-020
- Compliant to RoHS directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

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- Adapters
- For switching power supply
- Low stored charge
- Inverter

MECHANICAL DATA

- Case: SOD-523F
- Molding compound meets UL 94 V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 1A whisker test
- Polarity: Indicated by cathode band
- Weight: 1.68 ± 0.5 mg

KEY PARAMETERS			
PARAMETER	VALUE	UNIT	
I _F	200	mA	
V_{RRM}	30	V	
I _{FSM}	1	Α	
V _F at I _F =200mA	0.5	V	
T _J Max.	125	°C	
Package	SOD-523F		
Configuration	Single die		







ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)				
PARAMETER	SYMBOL	RB521S-30	UNIT	
Marking code on the device		С		
Power dissipation	P _D	200	mW	
Repetitive peak reverse voltage	V_{RRM}	30	V	
Forward current	I _F	200	mA	
Non-repetitive peak forward surge current @ t = 8.3ms	I _{FSM}	1	Α	
Junction temperature range	T _J	-55 to +125	°C	
Storage temperature range	T _{STG}	-55 to +125	°C	

THERMAL PERFORMANCE				
PARAMETER	SYMBOL	TYP	UNIT	
Junction-to-ambient thermal resistance	$R_{\Theta JA}$	500	°C/W	

1 Version: C1804



Taiwan Semiconductor

ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)					
PARAMETER	CONDITIONS	SYMBOL	MIN	MAX	UNIT
Forward voltage per diode (1)	I _F = 200mA, T _J = 25°C	V_{F}	-	0.5	V
Reverse breakdown voltage	I _R = 500 μA, T _J = 25°C	$V_{(BR)}$	30	-	V
Reverse leakage current (2)	V _R =10V, T _J = 25°C	I _R	-	30	μA

Notes:

- 1. Pulse test with PW=0.3 ms
- 2. Pulse test with PW=30 ms

ORDERING INFORMATION			
PART NO.	PACKAGE	PACKING	
RB521S-30 RKG	SOD-523F	3K / 7" Reel	
RB521S-30 RK	SOD-523F	3K / 7" Reel	



CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

Fig. 1 Forward Characteristics

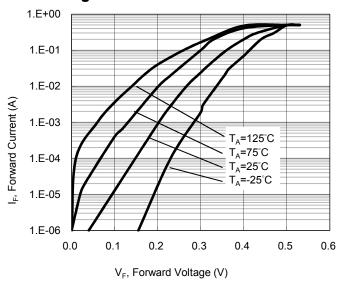


Fig. 2 Reverse Characteristics

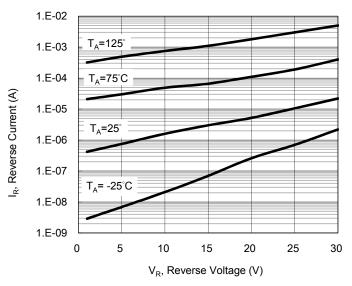
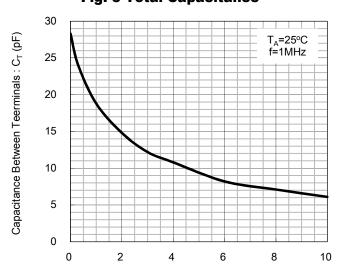


Fig. 3 Total Capacitance



Reverse Voltage : V_R (V)

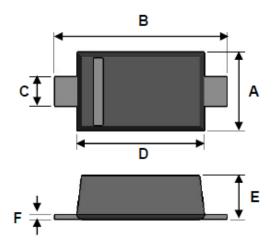
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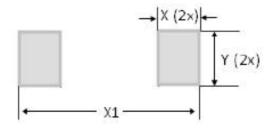
PACKAGE OUTLINE DIMENSION

SOD-523F



DIM	Unit (mm)		Unit (inch)		
DIM.	Min	Max	Min	Max	
Α	0.70	0.90	0.028	0.035	
В	1.50	1.70	0.059	0.067	
С	0.25	0.40	0.010	0.016	
D	1.10	1.30	0.043	0.051	
Е	0.50	0.77	0.020	0.030	
F	0.07	0.20	0.003	0.008	

SUGGEST PAD LAYOUT



DIM	Unit (mm)	Unit (inch)
DIM.	Тур.	Тур.
Х	0.60	0.024
X1	2.30	0.091
Y	0.80	0.031

4 Version: C1804



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